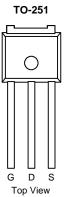
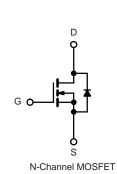


AP9962GJ-VB Datasheet

N-Channel 40 V (D-S) MOSFET

PRODUCT SUMMARY							
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)	Q _g (Typ.)				
40	0.0F3 at V _{GS} = 10 V	55 ^d	F9.5				
40	0.0Fl at V _{GS} = 4.5 V	I 5 ^d	19.5				





FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- VBmos® Trench Cell
- 100 % Rg and UIS Tested
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Power Supply
- Secondary Synchronous Rectification
- DC/DC Converter

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	40	Ň		
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current (T ₁ = 150 °C)	T _C = 25 °C	1-	55 ^d		
Continuous Drain Current (1) = 150°C)	T _C = 70 °C	I _D	I 5 ^d	•	
Pulsed Drain Current		I _{DM}	165	A	
Avalanche Current		I _{AS}	H4		
Single Avalanche Energy ^a	L = 0.1 mH	E _{AS}	Ϊ8	mJ	
	T _C = 25 °C	Р	Í 5.5 ^b	10/	
Maximum Power Dissipation ^a	T _A = 25 °C ^c	– P _D –	2.7	W	
Operating Junction and Storage Temperature Rar	nge	T _J , T _{stq}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Limit	Unit		
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	Í 4	°C/W		
Junction-to-Case (Drain)	R _{thJC}	2.Ï	0/10		

Notes:

a. Duty cycle \leq 1 %.

b. See SOA curve for voltage derating.c. When mounted on 1" square PCB (FR-4 material).

d. Package limited.

FREE

SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static		-	•				
Drain-Source Breakdown Voltage	V _{DS}	V _{DS} = 0 V, I _D = 250 μA	40			V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$	1		2.5	v	
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V			± 250	nA	
		V_{DS} = 40V, V_{GS} = 0 V			1		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 40V, V_{GS} = 0 V, T_{J} = 125 °C			50	μA	
		V_{DS} = 40V , V_{GS} = 0 V, T_{J} = 150 °C			250		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge$ 10 V, V_{GS} = 10 V	55			Α	
Drain-Source On-State Resistance ^a	Б	V _{GS} = 10 V, I _D = 22 A		0.0F3		Ω	
	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 20 A		0.0FI			
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		1€0		S	
Dynamic ^b							
Input Capacitance	C _{iss}			1100		pF	
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = 15 V, f = 1 MHz		460			
Reverse Transfer Capacitance	C _{rss}			350			
Total Gate Charge ^c	Qg	V_{DS} = 15 V, V_{GS} = 10 V, I_{D} = 20 A		H6			
Iotal Gate Charge				25		nC	
Gate-Source Charge ^c	Q _{gs}	$V_{\rm DS}$ = 15 V, $V_{\rm GS}$ = 4.5 V, $I_{\rm D}$ = 20 A		Î			
Gate-Drain Charge ^c	Q _{gd}			Í .7			
Gate Resistance	Rg	f = 1 MHz	0.4	2	4	Ω	
Turn-On Delay Time ^c	t _{d(on)}			8	16	ns	
Rise Time ^c	t _r	V _{DD} = 15 V, R _L = 1.5 Ω		9	18		
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong$ 10 A, V_{GEN} = 10 V, R_g = 1 Ω		35	53		
Fall Time ^c	t _f			9	18		
Drain-Source Body Diode Ratings a	nd Characteri	stics T _C = 25 °C ^b	•				
Continuous Current	۱ _S				55	^	
Pulsed Current	I _{SM}				165	— A	
Forward Voltage ^a	V _{SD}	I _F = 10 A, V _{GS} = 0 V		0.75	1.5	V	
Reverse Recovery Time	t _{rr}			34	51	ns	
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = 10 A, dI/dt = 100 A/μs		2	3	А	
Reverse Recovery Charge	Q _{rr}			34	51	nC	

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

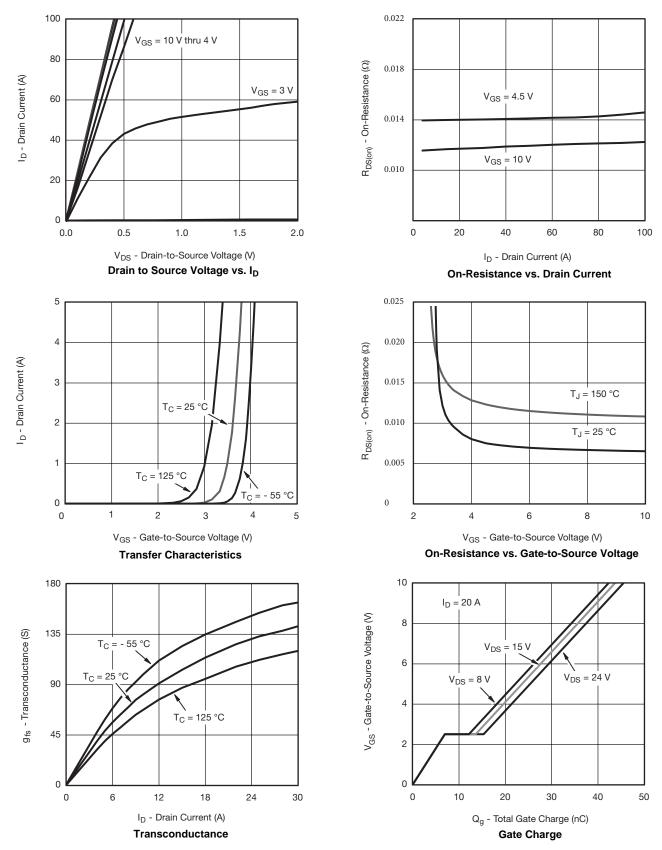
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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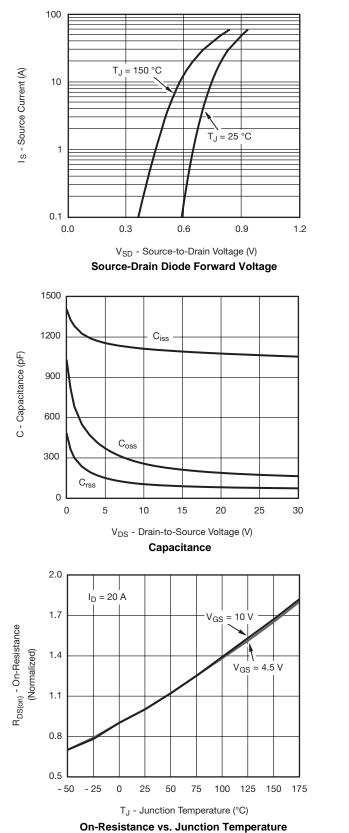




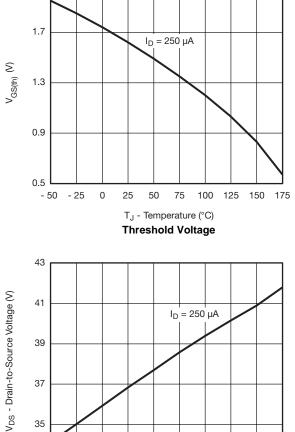


服务热线:400-655-8788

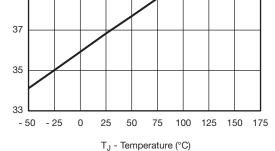


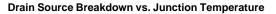


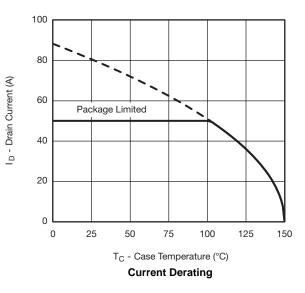
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



2.1

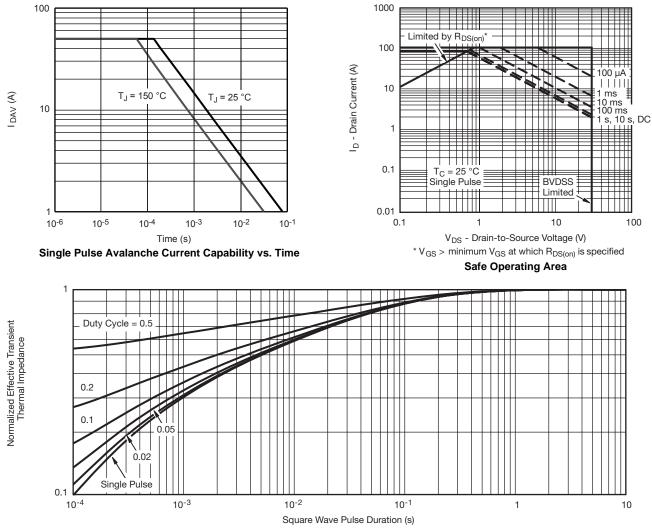










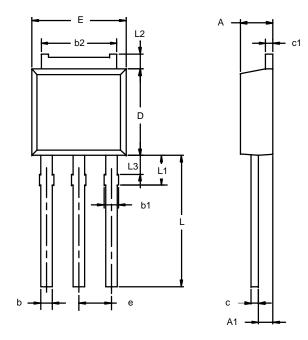


Normalized Thermal Transient Impedance, Junction-to-Case

AP9962GJ-VB



TO-251AA



	MILLIM	IETERS	INC	HES	
Dim	Min	Max	Min	Max	
Α	2.21	2.38	0.087	0.094	
A1	0.89	1.14	0.035	0.045	
b	0.71	0.89	0.028	0.035	
b1	0.76	1.14	0.030	0.045	
b2	5.23	5.43	0.206	0.214	
С	0.46	0.58	0.018	0.023	
c1	0.46	0.58	0.018	0.023	
D	5.97	6.22	0.235	0.245	
E	6.48	6.73	0.255	0.265	
е	2.28 BSC		0.090 BSC		
L	3.89	9.53	0.153	0.375	
L1	1.91	2.28	0.075	0.090	
L2	0.89	1.27	0.035	0.050	
L3	1.15	1.52	0.045	0.060	
ECN: S-03946—Rev. E, 09-Jul-01 DWG: 5346					

Note: Dimension L3 is for reference only.



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